# LV5683P

## BI-CMOSIC Multi Voltage Regulator IC for Car Audio Systems

### Overview

The LV5683P is a multi voltage regulator suitable for USB silicon tuner car-audio systems. This IC has 4 outputs,  $V_{DD}$  5V(3.3V), AUDIO(8.5V), SWU(3.3V) and USB5V(CD 8V: available). About protection circuits, it has Over-current-protection, Over-voltage-protection and Thermal-shut-down. V<sub>CC</sub>1(SWU and USB supply) is independent terminal from V<sub>CC</sub>, and accepts lower voltage (ex. From DC/DC converter) which enables to reduce power dissipation.





HZIP15

## Features

4 system regulator

| V <sub>DD</sub> (LCD micon) | : V <sub>OUT</sub> 5.0V(3.3V), I <sub>O</sub> max 300mA, |
|-----------------------------|--|
|                             | reverse current prevention.                              |
| Audio                       | : VOUT 8.5V, IO max 400mA                                |
| SWU(systems)                | : VOUT 3.3V, IO max 500mA                                |
| USB                         | : VOUT 5.0V(8.0V available for CD),                      |
|                             | IO max 1100mA  |

- Over-current-protection
- Thermal-shut-down Typ 175°C
- Over-voltage-protection: Typ 21V(except VDD)
- Applied Pch-LDMOS for output stages.

(Warning)The protector functions only improve the IC's tolerance and they do not guarantee the safety of the IC if used under the conditions out of safety range or ratings. Use of the IC such as use under overcurrent protection range or thermal shut down state may degrade the IC's reliability and eventually damage the IC.

## Specifications

#### **Absolute Maximum Ratings** at Ta = 25°C

| Parameter                          | Conditions           | Conditions                                  | Ratings     | Unit |
|------------------------------------|----------------------|---|-------------|------|
| Supply voltage                     | V <sub>CC</sub> max  |   | 36          | V    |
| Allowable Power dissipation Pd max |                      | IC unit                                     | 1.3         | W    |
|                                    | (*Ta ≤ 25°C)         | With AI heatsink(50×50×1.5mm <sup>3</sup> ) | 5.3         | W    |
|                                    |                      | Infinite heat rediation                     | 26          | W    |
| Peak supply voltage                | V <sub>CC</sub> peak | See below pulse wave.                       | 50          | V    |
| Operating ambient temperature      | Topr                 |   | -40 to +85  | °C   |
| Storage temperature                | Tstg                 |   | -55 to +150 | °C   |
| Junction temperature               | Tj max               |   | 150         | °C   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 10 of this data sheet.

#### Peak voltage testing pulse wave



## Recommended Operating condition at $Ta=25^{\circ}C$

| Parameter                     | Conditions   | Ratings    | Unit |
|-------------------------------|--|------------|------|
| Power supply voltage rating 1 | V <sub>DD</sub> output(5V/3.3V)                                | 7 to 16    | V    |
| Power supply voltage rating 2 | USB(5V) output, SWU output: V <sub>CC</sub> =V <sub>CC</sub> 1 | 7.5 to 16  | V    |
| Power supply voltage rating 3 | AUDIO output   | 10 to 16   | V    |
| Power supply voltage rating 4 | USB(8V) output: V <sub>CC</sub> =V <sub>CC</sub> 1             | 10.5 to 16 | V    |

## Electrical Characteristics at Ta = $25^{\circ}$ C, V<sub>CC</sub> = V<sub>CC</sub>1 = 14.4V (\*1)

| Parameter  | Symbol Conditions  |  | Ratings |        |      | Unit |  |
|--|--|--|---------|--------|------|------|--|
| - diamotor   | Cy501  | -,   |         | typ    | max  |      |  |
| Quiescent current $I_{CC}$ $V_{DD}$ no load, ALL EN terminal = $\lfloor L \rfloor$ |  |  | 50      | 100    | μA   |      |  |
| AUDIO_EN Input   |  |  |         |        |      |      |  |
| Low input voltage  | V <sub>IL</sub> 1  |  | 0       |        | 0.5  | V    |  |
| High input voltage   | V <sub>IH</sub> 1  |  | 2.8     |        | 5.5  | V    |  |
| Input impedance  | R <sub>IN</sub> 1  |  | 280     | 400    | 520  | kΩ   |  |
| SWU_EN Input   |  |  |         |        |      |      |  |
| Low input voltage  | V <sub>IL</sub> 2  |  | 0       |        | 0.5  | V    |  |
| High input voltage   | V <sub>IH</sub> 2  |  | 2.8     |        | 5.5  | V    |  |
| Input impedance  | R <sub>IN</sub> 2  |  | 280     | 400    | 520  | kΩ   |  |
| USB_EN input   | •  | ·  | · •     |        |      |      |  |
| Low input voltage  | V <sub>IL</sub> 3  |  | 0       |        | 0.5  | V    |  |
| High input voltage   | V <sub>IH</sub> 3  |  | 2.8     |        | 5.5  | V    |  |
| Input impedance  | R <sub>IN</sub> 3  |  | 280     | 400    | 520  | kΩ   |  |
| V <sub>DD</sub> (5V/3.3V)output(revers   | e current preventio  | on diode implemented)  | •       |        |      |      |  |
| V <sub>DD</sub> output voltage 1   | V <sub>O</sub> 11  | I <sub>O</sub> 11 = 200mA, IKV <sub>DD</sub> =OPEN, or V <sub>DD</sub> out | 4.75    | 5.0    | 5.25 | V    |  |
| V <sub>DD</sub> output current 1   | I <sub>O</sub> 11  | $V_011 \ge 4.7V$   | 300     |        |      | mA   |  |
| V <sub>DD</sub> output voltage 2   | V <sub>O</sub> 12  | I <sub>O</sub> 12 = 200mA, IKV <sub>DD</sub> =GND                          | 3.13    | 3.3    | 3.47 | V    |  |
| V <sub>DD</sub> output current 2   | I <sub>O</sub> 12  | I <sub>O</sub> 12 V <sub>O</sub> 12 ≥ 3.1V                                 |         |        |      | mA   |  |
| Line regulation  | ∆V <sub>OLN</sub> 1  | 7V < V <sub>CC</sub> < 16V, I <sub>O</sub> 1 = 200mA                       |         | 50     | 100  | mV   |  |
| Load regulation  | ΔV <sub>OLD</sub> 1  | 1mA < I <sub>O</sub> 11, I <sub>O</sub> 12 < 200mA                         |         | 80     | 150  | mV   |  |
| Dropout voltage 1  | V <sub>DROP</sub> 1  | I <sub>O</sub> 1 = 200mA (implemented diode)                               |         | 1.5    | 2.5  | V    |  |
| V <sub>CC</sub> ripple rejection   | R <sub>REJ</sub> 1   | f=120Hz, V <sub>CC</sub> =1V <sub>PP</sub> , I <sub>O</sub> 1=200mA        | 40(*2)  | 50(*2) |      | dB   |  |
| V <sub>DD</sub> reverse current  | I <sub>REV</sub>   | V <sub>O</sub> 11=5.0V, V <sub>CC</sub> =0V                                |         | 10     | 100  | μA   |  |
| USB/CD output ; USB_EN =   | High   |  |         |        |      |      |  |
| USB output voltage 1   | V <sub>O</sub> 21  | I <sub>O</sub> 21 = 1000mA, IKUSB=OPEN, or USBout                          | 7.6     | 8.0    | 8.4  | V    |  |
| USB output current 1   | I <sub>O</sub> 21  | V <sub>O</sub> 21 ≥ 7.45V  | 1100    | ľ      |      | mA   |  |
| USB output voltage 2   | V <sub>O</sub> 22  | I <sub>O</sub> 22 = 1000mA, IKUSB=GND                                      | 4.75    | 5.0    | 5.25 | V    |  |
| USB output current 2   | I <sub>O</sub> 22  | $V_022 \ge 4.6V$   | 1100    |        |      | mA   |  |
| Line regulation  | ΔV <sub>OLN</sub> 2  | 10.5V < V <sub>CC</sub> 1 < 16V, I <sub>O</sub> 2 = 1000mA                 |         | 50     | 100  | mV   |  |
| Load regulation  | ΔV <sub>OLD</sub> 2 10mA < I <sub>O</sub> 21, I <sub>O</sub> 22 < 1000mA |  |         | 100    | 200  | mV   |  |
| Dropout voltage  | V <sub>DROP</sub> 2  | I <sub>O</sub> 21, I <sub>O</sub> 22 = 1000mA                              |         | 1.0    | 2.0  | V    |  |
| V <sub>CC</sub> 1 ripple rejection   | R <sub>REJ</sub> 2   | f=120Hz, V <sub>CC</sub> 1=1V <sub>PP</sub> , I <sub>O</sub> 2=1000mA      | 40(*2)  | 50(*2) |      | dB   |  |

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|   | O week at          |  |        | Ratings |      |      |
|---|--------------------|--|--------|---------|------|------|
| Parameter   | Symbol             | Conditions   | min    | typ     | max  | Unit |
| AUDIO output ; AUDIO_EN = H   | igh                |  |        |         |      |      |
| AUDIO output voltage  | V <sub>O</sub> 3   | I <sub>O</sub> 3 = 300mA   | 8.1    | 8.5     | 8.9  | V    |
| AUDIO output current  | I <sub>O</sub> 3   | $V_{O}3 \ge 8V$  | 400    |         |      | mA   |
| Line regulation $\Delta V_{OLN}$ 3 10V < V <sub>CC</sub> < 16V, I <sub>O</sub> 3 = 10V < V <sub>CC</sub> < 16V, I <sub>O</sub> 3 = 10V < V <sub>CC</sub> < 16V, I <sub>O</sub> 3 = 10V < 10 |                    | $10V < V_{CC} < 16V, I_O3 = 300mA$                                     |        | 30      | 100  | mV   |
| Load regulation   | $\Delta V_{OLD}3$  | 1mA < I <sub>O</sub> 3 < 300mA   |        | 70      | 140  | mV   |
| Dropout voltage V <sub>DROP</sub> 3 I <sub>O</sub> 3 = 30   |                    | I <sub>O</sub> 3 = 300mA   |        | 0.6     | 1.05 | V    |
| V <sub>CC</sub> ripple rejection  | R <sub>REJ</sub> 3 | f = 120Hz, V <sub>CC</sub> =1V <sub>PP</sub> , I <sub>O</sub> 3=300mA  | 40(*2) | 50(*2)  |      | dB   |
| SWU (3.3V) Output ; SEU_EN =  | = High             |  |        |         |      |      |
| SWU output voltage  | V <sub>O</sub> 4   | I <sub>O</sub> 4 = 400mA   | 3.13   | 3.3     | 3.47 | V    |
| SWU output current  | I <sub>O</sub> 4   | $V_0 4 \ge 3.1V$   | 500    |         |      | mA   |
| Line regulation   | $\Delta V_{OLN}4$  | $7.5V < V_{CC}1 < 16V, I_{O}4 = 400mA$                                 |        | 30      | 100  | mV   |
| Load regulation   | $\Delta V_{OLD}4$  | 1mA < I <sub>O</sub> 4 < 400mA   |        | 80      | 150  | mV   |
| V <sub>CC</sub> 1 ripple rejection  | R <sub>REJ</sub> 4 | f = 120Hz, V <sub>CC</sub> 1=1V <sub>PP</sub> , I <sub>O</sub> 4=400mA | 40(*2) | 50(*2)  |      | dB   |

\*1: The entire specification has been defined based on the tests performed under the conditions where Tj and Ta(=25°C) are almost equal. There tests were performed with pulse load to minimize the increase of junction temperature(Tj).

\*2 : design certification

#### Allowable power dissipation derating curve



- (a) IC unit(HZIP15)
- (b) With Al heatsink(50×50×1.5mm<sup>3</sup>) Al heatsink mounting conditions Tightening torque: 39N⋅cm, using silicone grease

## Package Dimensions

unit : mm

#### HZIP15





NOTE: The measurements are not to guarantee but for reference only. \*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## Pin assignment



## **Block Diagram**



| Pin Fu  | Pin Function      |  |   |  |  |  |  |  |
|---------|-------------------|--|---|--|--|--|--|--|
| Pin No. | Pin name          | Description  | Equivalent Circuit  |  |  |  |  |  |
| 1       | N.C.              | -  |   |  |  |  |  |  |
| 2       | AUDIO_EN          | AUDIO output CTRL  | (2) + (1) |  |  |  |  |  |
| 3       | AUDIO             | AUDIO output when AUDIO_EN = High, ON<br>8.5V/0.4A   | $ \begin{array}{c}                                     $  |  |  |  |  |  |
| 4       | N.C.              | -  | -   |  |  |  |  |  |
| 5       | VDD               | V <sub>DD</sub> output<br>5.0V, 3.3V/0.3A  | $ \begin{array}{c}                                     $  |  |  |  |  |  |
| 6       | IKVDD             | V <sub>DD</sub> output voltage select<br>OPEN : V <sub>DD</sub> = 5.0V<br>GND : V <sub>DD</sub> = 3.3V | $ \begin{array}{c}                                     $  |  |  |  |  |  |
| 7       | N.C.              | -  | -   |  |  |  |  |  |
| 8       | Vcc               | Vcc  |   |  |  |  |  |  |
| 9       | V <sub>CC</sub> 1 | V <sub>CC</sub> 1  | (14) GND  |  |  |  |  |  |

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|----------|------------------|--|--|
| Pin No.  | Pin name         | Description  | Equivalent Circuit   |
| 10       | SWU_EN           | SWU output CTRL  |  |
|          |                  |  | (14)   |
| 11       | IKUSB            | USB output voltage select<br>OPEN : V <sub>DD</sub> = 8.0V<br>GND : V <sub>DD</sub> = 5.0V | $9 \qquad V_{CC1}$   |
| 12       | USB_EN           | USB output CTRL  | $9 \qquad V_{CC1}$   |
| 13       | USB              | USB output when USB_EN = High, ON<br>5.0V, 8.0V/1.1A                                       | $9$ $13$ $136k\Omega$ $13$ $136k\Omega$ $13$ $136k\Omega$ $10k\Omega$ $110k\Omega$ $110k\Omega$ $110$ $10$ $0$ $0$ $0$ $0$ $0$ $0$ $0$ $0$ $0$   |
| 14<br>15 | GND<br>SWU       | GND<br>SWU output when SWU_EN = High, ON<br>3.3V/0.5A                                      | 9<br>15<br>$75k\Omega$<br>$45k\Omega$<br>$45k\Omega$<br>14<br>CC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>VcC1<br>V |



#### HZIP15 Heat sink attachment

Heat sinks are used to lower the semiconductor device junction temperature by leading the head generated by the device to the outer environment and dissipating that heat.

- a. Unless otherwise specified, for power ICs with tabs and power ICs with attached heat sinks, solder must not be applied to the heat sink or tabs.
- b. Heat sink attachment
  - $\cdot$  Use flat-head screws to attach heat sinks.
  - $\cdot$  Use also washer to protect the package.
  - $\cdot$  Use tightening torques in the ranges 39-59Ncm(4-6kgcm) .
  - If tapping screws are used, do not use screws with a diameter larger than the holes in the semiconductor device itself.
  - Do not make gap, dust, or other contaminants to get between the semiconductor device and the tab or heat sink.
  - Take care a position of via hole .
  - $\cdot$  Do not allow dirt, dust, or other contaminants to get between the semiconductor device and the tab or heat sink.
  - $\cdot$  Verify that there are no press burrs or screw-hole burrs on the heat sink.
  - · Warping in heat sinks and printed circuit boards must be no more than
  - 0.05 mm between screw holes, for either concave or convex warping.
  - $\cdot$  Twisting must be limited to under 0.05 mm.
  - Heat sink and semiconductor device are mounted in parallel.
  - Take care of electric or compressed air drivers
  - The speed of these torque wrenches should never exceed 700 rpm, and should typically be about 400 rpm.
- c. Silicone grease
  - $\cdot$  Spread the silicone grease evenly when mounting heat sinks.
  - · Our company recommends YG-6260 (Momentive Performance Materials Japan LLC)

#### d. Mount

- · First mount the heat sink on the semiconductor device, and then mount that assembly on the printed circuit board.
- $\cdot$  When attaching a heat sink after mounting a semiconductor device into the printed circuit board, when tightening up a heat sink with the screw, the mechanical stress which is impossible to the semiconductor device and the pin doesn't hang.
- e. When mounting the semiconductor device to the heat sink using jigs, etc.,
  - $\cdot$  Take care not to allow the device to ride onto the jig or positioning dowel.
  - · Design the jig so that no unreasonable mechanical stress is not applied to the semiconductor device.
- f. Heat sink screw holes
  - · Be sure that chamfering and shear drop of heat sinks must not be larger than the diameter of screw head used.
  - When using nuts, do not make the heat sink hole diameters larger than the diameter of the head of the screws used. A hole diameter about 15% larger than the diameter of the screw is desirable.
  - $\cdot$  When tap screws are used, be sure that the diameter of the holes in the heat sink are not too small. A diameter about 15% smaller than the diameter of the screw is desirable.
- g. There is a method to mount the semiconductor device to the heat sink by using a spring band. But this method is not recommended because of possible displacement due to fluctuation of the spring force with time or vibration.





#### **ORDERING INFORMATION**

| Device    | Package             | Shipping (Qty / Packing) |
|-----------|---------------------|--------------------------|
| LV5683P-E | HZIP15<br>(Pb-Free) | 20 / Fan-Fold            |

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